Quantifying perpendicular magnetic anisotropy at the Fe-MgO(001) interface

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We show that Fe-MgO interfaces possess strong perpendicular magnetic anisotropy of 1.0 ± 0.1 erg/cm² in fully epitaxial MgO/V/Fe/MgO(001) and MgO/Cr/Fe/MgO(001) heterostructures. The sign and amplitude of the total anisotropy are quantified as a function of Fe thickness using magnetometry and ferromagnetic resonance. There is a transition from out-of-plane to in-plane anisotropy for 6 Fe monolayers in V/Fe/MgO and only 4 monolayers in Cr/Fe/MgO. A detailed study of the Fe magnetization and effective anisotropy in both systems explains this difference and quantifies the Fe-MgO interface anisotropy. © 2013 American Institute of Physics.

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The implementation of films with perpendicular magnetic anisotropy (PMA) enables a broad range of magnetic nanotechnologies. PMA materials have been implemented in hard disk drives for more than a decade delaying the onset of the superparamagnetic limit and are also the basis for prototype bit-patterned media.1 There is current interest in integrating PMA materials into spin transfer torque magnetic random access memory (STT-MRAM) as PMA materials provide a pathway to low critical current and high thermal stability.2

Perpendicular STT-MRAM devices need to combine large tunnel magnetoresistance (TMR) to read the information and large spin torque efficiency to switch magnetization with a polarised current. This has been largely achieved through the discovery of PMA in CoFeB/MgO/CoFeB magnetic tunnel junctions.3–7 It has further been shown that the PMA can be tuned by the application of a voltage.8–12 Theoretical analyses highlight different possible mechanisms that would lead to PMA and generally involves band hybridization, spin-orbit coupling splitting or strain.13–15 Particularly, Yang et al. attributed the PMA to a combination of two factors: overlap between O-pz and transition metal dz² orbitals, as well as degeneracy lift of out-of-plane 3d orbitals induced by spin-orbit coupling.14 In addition, He and Chen have shown that the lattice mismatch between MgO and FeCo could also induce an additional PMA.15 Predicted PMA amplitudes can reach 1.46 erg/cm² in Ref. 14 and 1.9 erg/cm² in Ref. 15 per Fe-MgO interface. Such values are more than 2 times larger than the value predicted for other interface-induced PMA like in Co/Pd, Co/Pt, Fe/Au, Fe/Au, or Co/Ni.16

Many recent experimental reports deal with tuning PMA and demonstrating the role of FeₓCo₁₋ₓ/MgO interface. Effect of buffer/cap, inserted Mg layer, MgO thickness, FeₓCo₁₋ₓ concentration, CoFeB annealing,3–7 and electric charges17,18 has been investigated. Besides, similar papers have focused on Co/AIOₓ interfaces19,20 and FePd/MgO.21 Most of these recent experimental results confirm that FeₓCo₁₋ₓ/MgO provides an anisotropy that is perpendicular to the interface. However, the amplitude of PMA anisotropy found in the literature shows a large spectrum of PMA amplitude6–9,17,18 and the largest values stay much below the theoretical predictions.1 One could argue that CoFeB-MgO interfaces obtained by sputtering exhibit structural defects whereas perfect interfaces are generally assumed in calculations. However even in molecular beam epitaxy (MBE) grown Au/Fe/MgO system, the Fe/MgO magnetic anisotropy is found to be much lower than the Au/Fe one, i.e., lower than 0.5 erg/cm².5,9,10

In this letter, we present a careful study of the magnetic features of MBE-grown single-crystal MgO/V/Fe/MgO (001) and MgO/Cr/Fe/MgO (001) heterostructures. Magnetization and magnetic anisotropies are measured by different techniques including magneto-optic Kerr effect (MOKE), ferromagnetic resonance (FMR), and magnetometry for Fe thickness ranging from 5 to 12 monoatomic layers (MLs). By considering the contributions of the Fe magneto-crystalline and shape anisotropies, and the V-Fe, Cr-Fe and Fe-MgO interfaces anisotropies, we can quantify the Fe-MgO interface anisotropy and compare to existing experimental and theoretical results.

The samples were grown on single-crystal MgO (100) substrate using MBE with a base-pressure lower than 10⁻¹⁰ Torr. The V or Cr buffer layers were deposited at room temperature (RT) and then annealed at 600°C. An Fe wedge was then grown on the V or Cr buffer layers and covered with a 6-ML (1.2 nm) MgO(001) film. The typical stacking of a sample is thus V or Cr(10 nm)/Fe(tFe)/MgO(1.2 nm) where the Fe thickness tFe is varied from 5 to 12 MLs in 1 ML steps. Fe was deposited at RT with no further annealing and capped with MgO also at RT. The epitaxial relationship, growth mode, number of deposited MLs, and surface flatness were controlled in situ using reflection high energy electron diffraction (RHEED). Figures 1(a) and 1(b) show RHEED intensity oscillations recorded during the growth of Fe on Cr and V, respectively. The oscillation period corresponds to 1 ML, which allows accurate control of tFe and demonstrates layer-by-layer growth and a low surface roughness. The RHEED patterns in the insets confirm the (001) crystalline order for the Cr and V buffer layers and Fe magnetic layers.

Figure 2 shows magnetization curves measured using a Quantum Design SQUID-VSM on both V/Fe(5–7 MLs)/MgO
and Cr/Fe(3–5 MLs)/MgO systems for both in-plane and out-of-plane applied magnetic fields. For the thinnest Fe layers, we observed square out-of-plane loops indicating PMA for the system. For the V/Fe/MgO(001) wedge (Figs. 2(a)–2(c)), the preferential magnetization direction moves from out-of-plane to in-plane as Fe thickness increases from 5 to 7 MLs. In contrast for the Cr/Fe/MgO(001) wedge (Figs. 2(d)–2(f)), this transition occurs for 3–5 ML. Considering that the origin of the PMA in such thin Fe layers is thought to be primarily due to the Fe-MgO interface anisotropy, these results clearly show additional contributing factors.

This apparent contradiction results from the difference in the magnetization of the Fe layers in both systems. The measured areal magnetic moment (i.e., M divided by sample area in erg/cm²) should increase linearly with the Fe thickness. If the Fe atomic moment is the same for all Fe atoms in the film, the M_{area}(t_Fe) should be a straight line passing through 0, with a slope equal to the bulk Fe magnetization (about 1715 emu/cm³). It is indeed observed in the Cr/Fe/MgO system (see inset of Fig. 3). This means that the Fe atomic moment is similar in the whole film, and consequently also at the Cr/Fe interface. The V/Fe/MgO system does not behave the same way (inset in Fig. 3). If the M(t_Fe) slope in V/Fe/MgO is similar to the slope observed in Cr/Fe/MgO (corresponding to a magnetization of 1680 ± 50 emu/cm³ which is close to the bulk Fe value), the straight line fit clearly crosses zero for 0.3 nm. Such results suggest that there is a deadlayer thickness t_{dl} = 0.3 nm indicating 2 dead magnetic MLs in our V/Fe/MgO samples. This behavior is in fact not surprising since a reduction of Fe magnetization at the interface with V is known and has been explained by roughness, charge transfer, and anti-parallel polarization of the V.22,23 An oxygen contamination of the starting V(001) surface should also contribute to these magnetic dead layers in Fe grown at RT.24

The effective anisotropy constant K_{eff} was extracted from the area between the out-of-plane and in-plane loops in one of the hysteresis quadrants. The results are shown in Fig. 3 where we plot the result for the magnetic thickness (t_Fe = t_{dl}). We also measured the V/Fe/MgO wedge samples for t_Fe ranging from 7 to 12 MLs using MOKE and FMR. The FMR measurements used a coplanar waveguide connected to a vector network analyzer to both generate and record the signal. The external DC magnetic field was applied in-plane. Figure 4 shows the typical FMR profiles obtained for in-plane magnetized samples. Shift in the field resonance with in-plane applied field gives access to the effective anisotropy through the relation \( \omega_0 = \gamma [H_{ip} (H_{ip} + H_{Keff})]^{1/2} \) where \( \omega_0 \) is the frequency at resonance, \( \gamma \) is the magneto-mechanical ratio for an electron spin, \( H_{ip} \) is the static applied magnetic field, and \( H_{Keff} \) is the effective anisotropy field of the sample \( H_{Keff} = 2K_{eff}/M_s \) (Ref. 25) (we ignore here the small Fe cubic anisotropy). MOKE experiments were performed with an applied field perpendicular to the sample plane. For all samples, typical hard axis loops were recorded and anisotropy fields were extracted assuming a square in-plane loop. The results for various thicknesses are also shown in Fig. 3.

The values of effective anisotropies K_{eff} extracted from SQUID-VSM, FMR, and MOKE experiments are plotted in
The interfaces anisotropy acting in the Fe layer. The field for \( t_{Fe} \) (points) and simulations (lines) performed on V/Fe/MgO wedge with thickness of the film, but here we should take into account the magnetization in the film plane. The thickness \( t \) is the negative sign shows that this anisotropy term tends to align the magnetization in the film plane. The thickness \( t \) is the thickness of the film, but here we should take into account the demagnetization term.

There are two contributions in \( K_v \), one coming from the V-Fe or Cr-Fe interfaces, the other from the Fe-MgO one. V/Fe/V superlattices have been heavily studied in the past and in-plane anisotropy has always been reported for Fe thickness as low as 3 MLs. At low temperatures, Anisimov et al. found positive interface anisotropy of the order of few erg/cm\(^2\) that monotonically disappears as the temperature increases to RT. The value of \( K_v \) at Cr/Fe interface has been measured only once in Ref. 32 as +0.19 erg/cm\(^2\). To summarize, both data for Fe on Cr and on V in Fig. 3 are well described by Eq. (2) considering a negligible \( K_v \) contribution. Therefore only \( K_s \) is an unknown parameter in Eq. (2) and the accuracy on this extracted \( K_v \) value is very good yielding a value of 1.0 ± 0.1 erg/cm\(^2\). As the V-Fe interface anisotropy is very small, this means that this \( K_v \) value comes from the Fe/MgO interface. We should however observe a slightly higher total \( K_v \) in Cr/Fe/MgO since the Cr/Fe interface contribution is not negligible when compared to the extracted Fe-MgO one.

The extracted \( K_v \) value for Fe/MgO interface is larger than the value obtained in MBE-grown Au/Fe\(_x\)Co\(_{1-x}\)/MgO (<0.5 erg/cm\(^2\)) but smaller than in tuned CoFeB/MgO interfaces (1.6 erg/cm\(^2\)). Such a dispersion of the \( K_v \) values is not negligible when compared to the extracted Fe-MgO one.

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in real systems are difficult to take into account in calculations and may decrease this interface anisotropy.

In summary, detailed analysis of magnetic properties (magnetization, effective anisotropy) allows us to enlighten the origin of PMA in V/Fe/MgO(001) and Cr/Fe/MgO(001) epitaxial layers. The Fe thickness limit for getting PMA is found to be different in both systems (below 6 MLs in V/Fe/MgO and 4 MLs in Cr/Fe/MgO). This is explained by the occurrence of 2 MLs magnetic dead layers in Fe on V that does not exist on Cr. For a given Fe thickness, the shape anisotropy is thus smaller in V/Fe than in Cr/Fe whereas the Fe/MgO interface anisotropy is found to be similar for both systems. This work allows an accurate and robust determination of the Fe/MgO interface anisotropy $K_s = 1.0 \pm 0.1$ erg/cm² ($\text{mJ/m}^2$) responsible for PMA. Such a high $K_s$ (around 2 times larger than in the low spin-orbit prototype Co/Ni(111) system) is very promising for further use in STT-RAM and spintronic systems.

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